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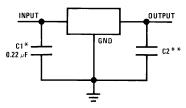
# LM140K 3 端子正稳压器

查询样品: LM140K

### 特性

- 1A 负载上的完整技术规格
- T<sub>i</sub> = 25°C 时, ±4% 的输出电压耐受
- 内部热过载保护
- 内部短路电流限制
- 输出晶体管安全区保护
- 已经测试了 P\*产品增强性能

### **Typical Applications**



\*Required if the regulator is located far from the power supply filter.

\*\*Although no output capacitor is needed for stability, it does help transient response. (If needed, use 0.1 µF, ceramic disc).

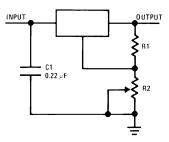
Figure 1. Fixed Output Regulator

### 说明

LM140K 单片 3 端子正电压稳压器采用内部电流限 制、热关断和安全区补偿,从而使得它们基本上不会被 损坏。 如果提供足够散热,它们能够提供超过 1.0A 的 输出电流。 它们在广泛应用中被用作固定电压稳压 器,这些应用包括旨在消除与单点稳压相关的噪声和配 电问题的本地(卡上)稳压。除了用作一个固定电压 稳压器,这些器件可与外部组件一同使用以获得可调输 出电压和电流。

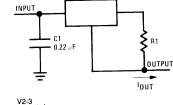
花费了大量的精力来使整个稳压器系列易于使用并且大 大减少了外部组件的数量。 虽然这的确改进了瞬态响 应,但是也没有必要将输出旁路。 只有当稳压器远离 电源的滤波电容器时,才需要输入旁路。

LM104K 采用钢制 TO-3 功率封装, 提供 5V, 12V 和 15V 电压选项。



 $V_{OUT} = 5V + (5V/R1 + I_Q) R2 5V/R1 > 3 I_Q,$ load regulation  $(L_r) \approx [(R1 + R2)/R1] (L_r \text{ of }$ LM140K-5.0).

Figure 2. Adjustable Output Regulator



 $I_{OUT} = \frac{V2-3}{R1} + I_{Q}$ 

 $\Delta I_{\rm O}$  = 1.3 mA over line and load changes.

Figure 3. Current Regulator

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### **Connection Diagrams**

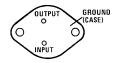


Figure 4. TO-3 Metal Can (Bottom View)



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

# **Absolute Maximum Ratings**(1)(2)(3)

DC Input Voltage	35V	
Internal Power Dissipation (4)	Internally Limited	
Maximum Junction Temperature	150°C	
Storage Temperature Range		−65°C to +150°C
Lead Temperature (Soldering, 10 sec.)	TO-3 Package (NDS)	300°C
ESD Susceptibility <sup>(5)</sup>		2 kV

- (1) Absolute Maximum Ratings are limits beyond which damage to the device may occur. Operating Conditions are conditions under which the device functions but the specifications might not be ensured. For ensured specifications and test conditions see the Electrical Characteristics
- (2) Specifications and availability for military grade LM140H/883 and LM140K/883 can be found in the LM140QML datasheet (SNVS382). Specifications and availability for military and space grade LM140H/JAN and LM140K/JAN can be found in the LM140JAN datasheet (SNVS399).
- (3) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.
- (4) The maximum allowable power dissipation at any ambient temperature is a function of the maximum junction temperature for operation (T<sub>JMAX</sub> = 125°C or 150°C), the junction-to-ambient thermal resistance (θ<sub>JA</sub>), and the ambient temperature (T<sub>A</sub>). P<sub>DMAX</sub> = (T<sub>JMAX</sub> ¬ T<sub>A</sub>)/θ<sub>JA</sub>. If this dissipation is exceeded, the die temperature will rise above T<sub>JMAX</sub> and the electrical specifications do not apply. If the die temperature rises above 150°C, the device will go into thermal shutdown. For the TO-3 package (NDS), the junction-to-ambient thermal resistance (θ<sub>JA</sub>) is 39°C/W. When using a heatsink, θ<sub>JA</sub> is the sum of the 4°C/W junction-to-case thermal resistance (θ<sub>JC</sub>) of the TO-3 package and the case-to-ambient thermal resistance of the heatsink.
- (5) ESD rating is based on the human body model, 100 pF discharged through 1.5 k $\Omega$ .

# Operating Conditions<sup>(1)</sup>

Temperature Range (T <sub>A</sub> ) <sup>(2)</sup>	LM140	−55°C to +125°C

- (1) Absolute Maximum Ratings are limits beyond which damage to the device may occur. Operating Conditions are conditions under which the device functions but the specifications might not be ensured. For ensured specifications and test conditions see the Electrical Characteristics.
- (2) The maximum allowable power dissipation at any ambient temperature is a function of the maximum junction temperature for operation (T<sub>JMAX</sub> = 125°C or 150°C), the junction-to-ambient thermal resistance (θ<sub>JA</sub>), and the ambient temperature (T<sub>A</sub>). P<sub>DMAX</sub> = (T<sub>JMAX</sub> ¬ T<sub>A</sub>)/θ<sub>JA</sub>. If this dissipation is exceeded, the die temperature will rise above T<sub>JMAX</sub> and the electrical specifications do not apply. If the die temperature rises above 150°C, the device will go into thermal shutdown. For the TO-3 package (NDS), the junction-to-ambient thermal resistance (θ<sub>JA</sub>) is 39°C/W. When using a heatsink, θ<sub>JA</sub> is the sum of the 4°C/W junction-to-case thermal resistance (θ<sub>JC</sub>) of the TO-3 package and the case-to-ambient thermal resistance of the heatsink.



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### **LM140 Electrical Characteristics**

 $55^{\circ}\text{C} \le \text{T}_{\perp} \le + 150^{\circ}\text{C}$  unless otherwise specified<sup>(1)</sup>

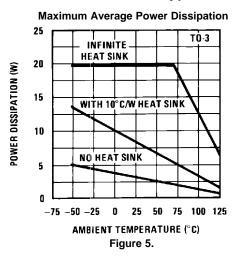
		Output Vo	Itage		5V		12V						
Symbol	Input Voltag	ge (unless		10V		19V				Units			
	Parameter		Conditions	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
Vo	Output	$T_J = 25^{\circ}C$	, 5 mA ≤ I <sub>O</sub> ≤ 1A	4.9	5	5.1	11.75	12	12.25	14.7	15	15.3	V
	Voltage	P <sub>D</sub> ≤ 15W	, 5 mA ≤ I <sub>O</sub> ≤ 1A	4.8		5.2	11.5		12.5	14.4		15.6	V
		$V_{MIN} \le V_{IN}$	$(7.5 \le V_{IN} \le 20)$			(14.8	$(14.8 \le V_{IN} \le 27)$		(17.	9 ≤ V <sub>IN</sub> :	≤ 30)	V	
$\Delta V_{O}$	Line Regulation	I <sub>O</sub> = 500 n	nA	10			18			22			mV
		T <sub>J</sub> = 25°C ≤ +150°C	, $\Delta$ V <sub>IN</sub> , −55°C ≤ T <sub>J</sub>	$(7.5 \le V_{IN} \le 20)$			$(14.8 \le V_{IN} \le 27)$			$(17.9 \le V_{IN} \le 30)$			V
		$T_J = 25^{\circ}C$		3 10			4 18			4 22			mV
		ΔV <sub>IN</sub> , −55	$^{\circ}$ C $\leq$ T <sub>J</sub> $\leq$ +150 $^{\circ}$ C	$(7.5 \le V_{IN} \le 20)$			$(14.5 \le V_{IN} \le 27)$			$(17.5 \le V_{IN} \le 30)$			V
		$T_J = 25^{\circ}C$		4 12			9					10	mV
		Over Tem	perature								mV		
		$\Delta V_{IN}$	_	(8 ≤ V <sub>IN</sub> ≤ 12)			(16 ≤ V <sub>IN</sub> ≤ 22)			(20 ≤ V <sub>IN</sub> ≤ 26)			V
$\Delta V_{O}$	Load	$T_J =$	$5 \text{ mA} \le I_{\text{O}} \le 1.5 \text{A}$		10	25		12	32		12	35	mV
	Regulation	25°C	250 mA ≤ I <sub>O</sub> ≤ 750 mA			15			19			21	mV
		Over Tem	perature,			25			60			75	mV
		5 mA ≤ I <sub>O</sub>	≤ 1A										
$I_Q$	Quiescent	$T_J = 25^{\circ}C$				6			6			6	mA
	Current	Over Tem	perature	6.5			6.5			6.5			mA
$\Delta I_Q$	Quiescent Current Change	5 mA ≤ I <sub>O</sub>	≤ 1A	0.5			0.5			0.5			mA
		$T_J = 25^{\circ}C$	$I_{O} = 1A$	0.8			0.8			0.8			mA
		$V_{MIN} \le V_{IN}$	<sub>1</sub> ≤ V <sub>MAX</sub>	$(7.5 \le V_{IN} \le 20)$			$(14.8 \le V_{IN} \le 27)$			$(17.9 \le V_{IN} \le 30)$			V
		$I_{O} = 500 \text{ n}$		0.8			0.8			0.8			mA
		$V_{MIN} \le V_{IN}$		$(8 \le V_{IN} \le 25)$			$(15 \le V_{IN} \le 30)$			$(17.9 \le V_{IN} \le 30)$			V
V <sub>N</sub>	Output Noise Voltage	kHz	c, 10 Hz ≤ f ≤ 100	40			75			90			μV
ΔV <sub>IN</sub>	Ripple Rejection	T <sub>J</sub> = 25°C 1A	, f = 120 Hz, I <sub>O</sub> =	68	80		61	72		60	70		dB
ΔV <sub>OUT</sub>		or f = 120	Hz, $I_O = 500$ mA,	68			61			60			dB
		Over Tem	perature,										
		$V_{MIN} \le V_{IN}$		(8 ≤ V <sub>IN</sub> ≤ 18)			$(15 \le V_{IN} \le 25)$			$(18.5 \le V_{IN} \le 28.5)$			V
R <sub>O</sub>	Dropout Voltage	$T_J = 25^{\circ}C$	, I <sub>O</sub> = 1A		2.0			2.0			2.0		V
	Output Resistance	f = 1 kHz			8			18			19		mΩ
	Short-Circuit Current	$T_J = 25^{\circ}C$			2.1		1.5				1.2		Α
	Peak Output Current	T <sub>J</sub> = 25°C		2.4			2.4				2.4		Α
	Average TC of V <sub>O</sub>	Min, T <sub>J</sub> =	0°C, I <sub>O</sub> = 5 mA	-0.6			-1.5			-1.8			mV/°C
V <sub>IN</sub>	Input Voltage Required to Maintain Line Regulation	T <sub>J</sub> = 25°C		7.5			14.5			17.5			V

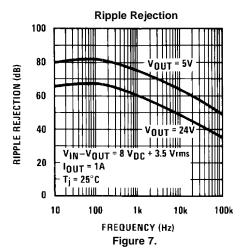
<sup>(1)</sup> All characteristics are measured with a 0.22 µF capacitor from input to ground and a 0.1 µF capacitor from output to ground. All characteristics except noise voltage and ripple rejection ratio are measured using pulse techniques (t<sub>w</sub> ≤ 10 ms, duty cycle ≤ 5%). Output voltage changes due to changes in internal temperature must be taken into account separately.

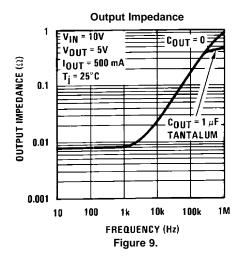
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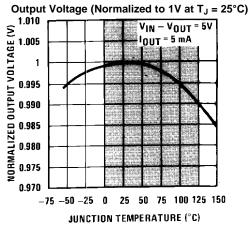
# TEXAS INSTRUMENTS

### **Typical Performance Characteristics**

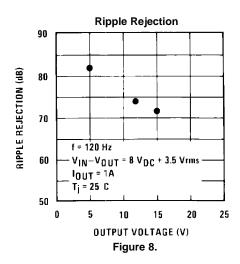


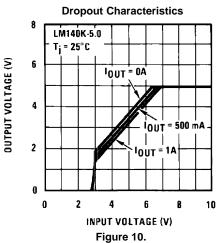








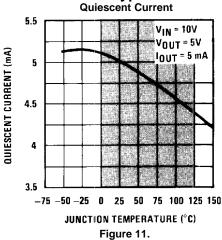






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# **Typical Performance Characteristics (continued)**



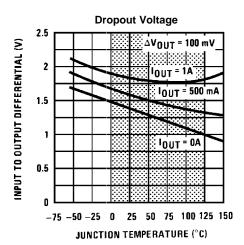
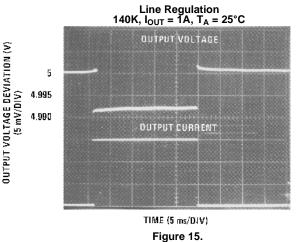


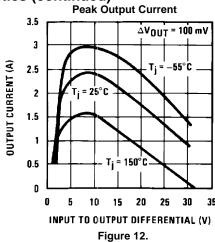
Figure 13.

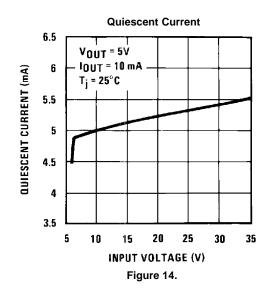


**OUTPUT CURRENT (A)** 

OUTPUT VOLTAGE DEVIATION (V) (5 mV/DIV)

1





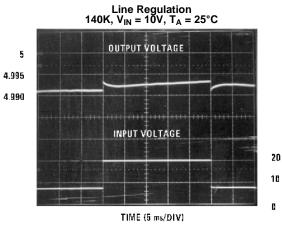


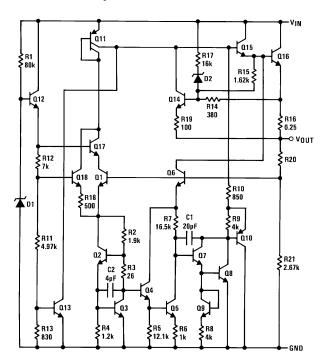
Figure 16.

INPUT VOLTAGE (V)

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# **Equivalent Schematic**





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### **APPLICATION HINTS**

The LM140K is designed with thermal protection, output short-circuit protection and output transistor safe area protection. However, as with *any* IC regulator, it becomes necessary to take precautions to assure that the regulator is not inadvertently damaged. The following describes possible misapplications and methods to prevent damage to the regulator.

### SHORTING THE REGULATOR INPUT

When using large capacitors at the output of these regulators, a protection diode connected input to output (Figure 17) may be required if the input is shorted to ground. Without the protection diode, an input short will cause the input to rapidly approach ground potential, while the output remains near the initial  $V_{OUT}$  because of the stored charge in the large output capacitor. The capacitor will then discharge through a large internal input to output diode and parasitic transistors. If the energy released by the capacitor is large enough, this diode, low current metal and the regulator will be destroyed. The fast diode in Figure 17 will shunt most of the capacitors discharge current around the regulator. Generally no protection diode is required for values of output capacitance  $\leq 10 \ \mu\text{F}$ .

### RAISING THE OUTPUT VOLTAGE ABOVE THE INPUT VOLTAGE

Since the output of the device does not sink current, forcing the output high can cause damage to internal low current paths in a manner similar to that just described in the "Shorting the Regulator Input" section.

### **REGULATOR FLOATING GROUND (Figure 18)**

When the ground pin alone becomes disconnected, the output approaches the unregulated input, causing possible damage to other circuits connected to  $V_{OUT}$ . If ground is reconnected with power "ON", damage may also occur to the regulator. This fault is most likely to occur when plugging in regulators or modules with on card regulators into powered up sockets. Power should be turned off first, thermal limit ceases operating, or ground should be connected first if power must be left on.

#### TRANSIENT VOLTAGES

If transients exceed the maximum rated input voltage of the device, or reach more than 0.8V below ground and have sufficient energy, they will damage the regulator. The solution is to use a large input capacitor, a series input breakdown diode, a choke, a transient suppressor or a combination of these.

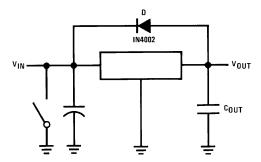


Figure 17. Input Short

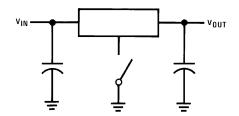


Figure 18. Regulator Floating Ground

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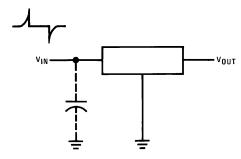
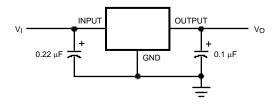


Figure 19. Transients

When a value for  $\theta_{(H-A)}$  is found using the equation shown, a heatsink must be selected that has a value that is less than or equal to this number.

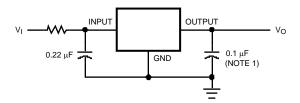
 $\theta_{(H-A)}$  is specified numerically by the heatsink manufacturer in this catalog, or shown in a curve that plots temperature rise vs power dissipation for the heatsink.

## **Typical Applications**



Bypass capacitors are recommended for optimum stability and transient response, and should be located as close as possible to the regulator.

Figure 20. Fixed Output Regulator



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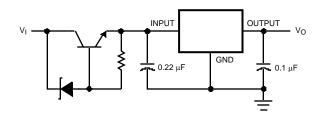
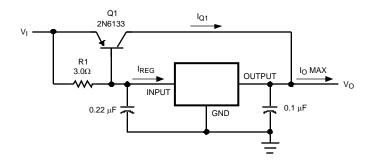
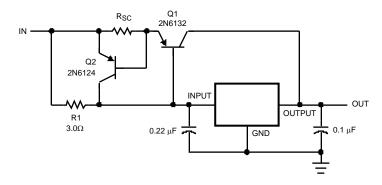


Figure 21. High Input Voltage Circuits



$$\begin{split} \beta(\text{Q1}) &\geq \frac{I_{\text{O Max}}}{I_{\text{REG Max}}} \\ \text{R1} &= \frac{0.9}{I_{\text{REG}}} = \frac{\beta(\text{Q1}) \, V_{\text{BE(Q1)}}}{I_{\text{REG Max}} (\beta \, + \, 1) \, - \, I_{\text{O Max}}} \end{split}$$

Figure 22. High Current Voltage Regulator



$$\begin{aligned} \mathsf{R}_{\mathsf{SC}} &= \frac{\mathsf{0.8}}{\mathsf{I}_{\mathsf{SC}}} \\ \mathsf{R1} &= \frac{\beta \mathsf{V}_{\mathsf{BE}(\mathsf{O1})}}{\mathsf{I}_{\mathsf{REG Max}} \left(\beta + 1\right) - \mathsf{I}_{\mathsf{O Max}}} \end{aligned}$$

Figure 23. High Output Current, Short Circuit Protected



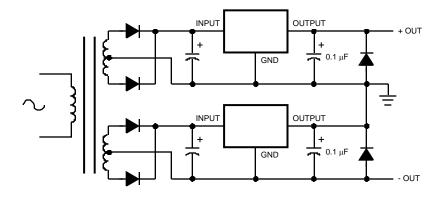


Figure 24. Positive and Negative Regulator





10-Dec-2020

#### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LM140K-12	ACTIVE	TO-3	NDS	2	50	Non-RoHS & Non-Green	Call TI	Call TI	-55 to 125	LM140K 12P+	Samples
LM140K-12/NOPB	ACTIVE	TO-3	NDS	2	50	RoHS & Green	Call TI	Level-1-NA-UNLIM	-55 to 125	LM140K 12P+	Samples
LM140K-15	ACTIVE	TO-3	NDS	2	50	Non-RoHS & Non-Green	Call TI	Call TI	-55 to 125	LM140K 15P+	Samples
LM140K-15/NOPB	ACTIVE	TO-3	NDS	2	50	RoHS & Green	Call TI	Level-1-NA-UNLIM	-55 to 125	LM140K 15P+	Samples
LM140K-5.0	ACTIVE	TO-3	NDS	2	50	Non-RoHS & Non-Green	Call TI	Call TI	-55 to 125	LM140K 5.0P+	Samples
LM140K-5.0/NOPB	ACTIVE	TO-3	NDS	2	50	RoHS & Green	Call TI	Level-1-NA-UNLIM	-55 to 125	LM140K 5.0P+	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



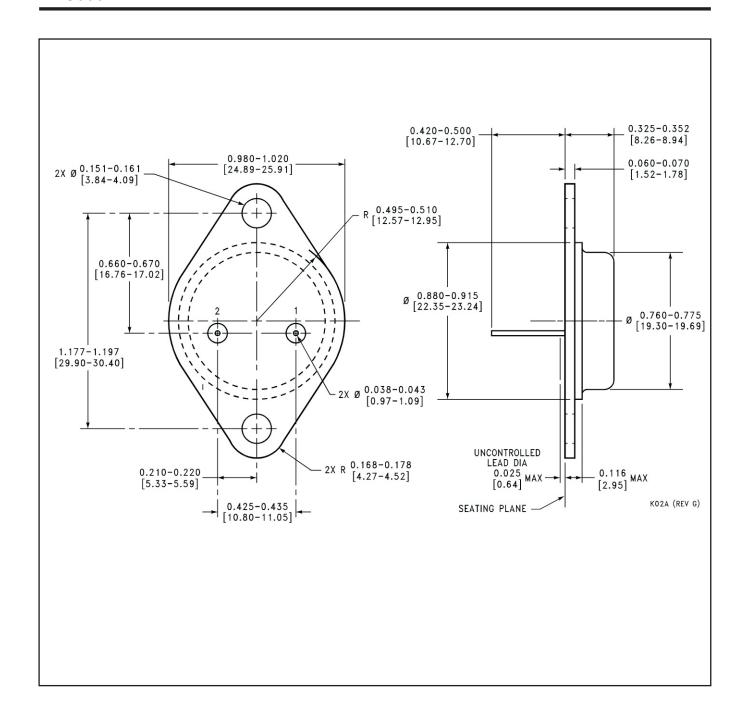
# PACKAGE OPTION ADDENDUM

10-Dec-2020

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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